



PCIe M.2 SSDs

# MTE470A & MTE470A-I

Transcend's M.2 SSD MTE470A is a self-encrypting drive (SED) that complies with the TCG Opal 2.0 standards. Data is protected using the hardware-based AES 256-bit encryption and LBA (Logical Block Address)sector-specific permissions.

Transcend's MTE470A M.2 SSD features 112 layers of 3D NAND flash and a PCI Express (PCIe) Gen 3 x4 interface, delivering never-before-seen transfer speeds. In addition, the 30μ" gold finger PCB, Corner Bond technology, and anti-sulfur resistors guarantee its reliability in harsh conditions. Transcend's MTE560I is also 100% chamber tested inhouse for extended operating temperatures of -20°C~75°C. Its M.2 2242 form factor is compact and portable, ideal for mobile computing applications. Wide Temperature (-40°C~85°C) is available upon request.

### Hardware Features

- · PCle Gen 3 x4 interface
- Anti-sulfur technology implemented to prevent sulfurization in the environment
- 30µ" PCB gold finger
- · Key components fortified by default with Corner Bond technology
- Power Shield (PS) to ensure data transfer integrity and minimize data corruption in the drive during an abnormal power outage

#### Firmware Features

- Supports S.M.A.R.T. function to conduct health monitoring, analysis, and reporting for storage devices
- · Dynamic thermal throttling
- Full drive encryption with Advanced Encryption Standard (AES)
- · Compliant with TCG Opal specifications and IEEE 1667 standards
- · Built-in LDPC ECC (Error Correction Code) functionality

#### \*Supports Microsoft® eDrive standard

## **Ordering Information**

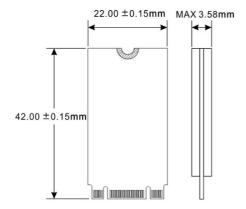
128GB	TS128GMTE470A TS128GMTE470A-I
256GB	TS256GMTE470A TS256GMTE470A-I
512GB	TS512GMTE470A TS512GMTE470A-I
1TB	TS1TMTE470A TS1TMTE470A-I
2TB	TS2TMTE470A TS2TMTE470A-I



## **Specifications**

Dimensions   42 mm x 22 mm x 2.23 mm (1.65" x 0.09")			
M.2 Type	Appearance	Dimensions	42 mm x 22 mm x 2.23 mm (1.65" x 0.87" x 0.09")
M.2 Type		Weight	5 g (0.18 oz)
Interface         Bus Interface         NVMe PCIe Gen3 x4           Storage         Capacity         128 GB / 256 GB / 512 GB / 1 TB / 2 TB           Flash Type         112-layer 3D NAND flash           Operating Temperature         Doperating Temperature         Extended Temp20°C (-4°F) ~ 75°C (167°F)           Wide Temp40°C (-40°F) ~ 85°C (185°F)           Humidity         5% ~ 95%           Shock         1500 G, 0.5 ms, 3 axis           Vibration (Operating)         20 G (peak-to-peak), 7 Hz ~ 2,000 Hz (frequency)           Power         Power Consumption (IDLE)         0.53 watt(s)           Performance         Sequential Read/Write (CrystalDiskMark)         Read: Up to 2,000 MB/s Write: Up to 1,700 MB/s           Write: Up to 105,000 IOPS Write: Up to 250,000 IOPS		M.2 Type	2242-S2-M
Capacity		Form Factor	M.2 2242
Storage         Flash Type         112-layer 3D NAND flash           Operating Voltage         3.3V±5%           Environment         Extended Temp.	Interface	Bus Interface	NVMe PCIe Gen3 x4
Plash Type	Storage	Capacity	128 GB / 256 GB / 512 GB / 1 TB / 2 TB
Operating Temperature         Extended Temp20°C (-4°F) ~ 75°C (167°F) Wide Temp40°C (-40°F) ~ 85°C (185°F)           Environment         Storage Temperature         -55°C (-67°F) ~ 85°C (185°F)           Humidity         5% ~ 95%           Shock         1500 G, 0.5 ms, 3 axis           Vibration (Operating)         20 G (peak-to-peak), 7 Hz ~ 2,000 Hz (frequency)           Power         Power Consumption (Operation)         4.3 watt(s)           Power Consumption (IDLE)         0.53 watt(s)           Read: Up to 2,000 MB/s Write: Up to 1,700 MB/s           Write: Up to 1,700 MB/s           Write: Up to 250,000 IOPS           Write: Up to 250,000 IOPS		Flash Type	112-layer 3D NAND flash
Operating         -20°C (-4°F) ~ 75°C (167°F)           Wide Temp.         -40°C (-40°F) ~ 85°C (185°F)           Environment         Storage Temperature         -55°C (-67°F) ~ 85°C (185°F)           Humidity         5% ~ 95%           Shock         1500 G, 0.5 ms, 3 axis           Vibration (Operating)         20 G (peak-to-peak), 7 Hz ~ 2,000 Hz (frequency)           Power         Power Consumption (Operation)         4.3 watt(s)           Power Consumption (IDLE)         0.53 watt(s)           Read: Up to 2,000 MB/s Write: Up to 1,700 MB/s           Write: Up to 1,700 MB/s           Write: Up to 250,000 IOPS Write: Up to 250,000 IOPS		Operating Voltage	3.3V±5%
Operating         Wide Temp.			
Humidity   5% ~ 95%     Shock   1500 G, 0.5 ms, 3 axis     Vibration (Operating)   20 G (peak-to-peak), 7 Hz ~ 2,000 Hz (frequency)     Power Consumption (Operation)   4.3 watt(s)     Power Consumption (IDLE)   0.53 watt(s)     Sequential Read/Write (CrystalDiskMark)   Read: Up to 2,000 MB/s     Write: Up to 1,700 MB/s     4K Random Read/Write (IOmeter)   Read: Up to 250,000 IOPS     Write: Up to 250,000 IOPS		Operating Temperature	· · · · · · · · · · · · · · · · · · ·
Shock  Vibration (Operating)  Power Consumption (Operation)  Power Consumption (IDLE)  Sequential Read/Write (CrystalDiskMark)  Write: Up to 1,700 MB/s  Write: Up to 250,000 IOPS  Write: Up to 250,000 IOPS		Storage Temperature	-55°C (-67°F) ~ 85°C (185°F)
Vibration (Operating)  20 G (peak-to-peak), 7 Hz ~ 2,000 Hz (frequency)  Power Consumption (Operation)  4.3 watt(s)  Power Consumption (IDLE)  0.53 watt(s)  Sequential Read/Write (CrystalDiskMark)  Read: Up to 2,000 MB/s Write: Up to 1,700 MB/s  4K Random Read/Write (IOmeter)  Read: Up to 105,000 IOPS Write: Up to 250,000 IOPS		Humidity	5% ~ 95%
Power Consumption (Operation) 4.3 watt(s)  Power Consumption (IDLE) 0.53 watt(s)  Sequential Read/Write (CrystalDiskMark)  Read: Up to 2,000 MB/s Write: Up to 1,700 MB/s  4K Random Read/Write (IOmeter)  Read: Up to 105,000 IOPS Write: Up to 250,000 IOPS		Shock	1500 G, 0.5 ms, 3 axis
Power Consumption (IDLE)  Sequential Read/Write (CrystalDiskMark)  4K Random Read/Write (IOmeter)  Read: Up to 2,000 MB/s Write: Up to 1,700 MB/s Read: Up to 105,000 IOPS Write: Up to 250,000 IOPS		Vibration (Operating)	20 G (peak-to-peak), 7 Hz ~ 2,000 Hz (frequency)
Power Consumption (IDLE)  Sequential Read/Write (CrystalDiskMark)  4K Random Read/Write (IOmeter)  Read: Up to 2,000 MB/s Write: Up to 1,700 MB/s  Read: Up to 105,000 IOPS  Write: Up to 250,000 IOPS	Power	Power Consumption (Operation)	4.3 watt(s)
Sequential Read/Write (CrystalDiskMark)  Write: Up to 1,700 MB/s  4K Random Read/Write (IOmeter)  Read: Up to 105,000 IOPS Write: Up to 250,000 IOPS		Power Consumption (IDLE)	0.53 watt(s)
Performance  Write: Up to 250,000 IOPS	Performance	Sequential Read/Write (CrystalDiskMark)	
		4K Random Read/Write (IOmeter)	
weath time between railules (WTDF) 3,000,000 flour(s)		Mean Time Between Failures (MTBF)	3,000,000 hour(s)
Terabytes Written (TBW) Up to 1800 TBW		Terabytes Written (TBW)	Up to 1800 TBW
Drive Writes Per Day (DWPD) 0.86 (3 yrs)		Drive Writes Per Day (DWPD)	0.86 (3 yrs)
Certificate CE / UKCA / FCC / BSMI	Warranty	Certificate	CE / UKCA / FCC / BSMI
Warranty Three-year Limited Warranty		Warranty	Three-year Limited Warranty

## **Mechanical Dimensions**



Product specifications are subject to change without notice. Pictures shown may differ from actual products. Total accessible capacity varies depending on operating environment. Due to the complexity and variety of industrial applications, Transcend cannot guarantee 100% compatibility with all platforms and under all scenarios. For special applications and environments, it is strongly suggested that you contact Transcend beforehand for clarification.